

## DC COMPONENTS CO., LTD.

### RECTIFIER SPECIALISTS

GS1A/M1 THRU GS1M/M7

# TECHNICAL SPECIFICATIONS OF SURFACE MOUNT SILICON RECTIFIER VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere

#### **FEATURES**

- \* Ideal for surface mounted applications
- \* Low leakage current
- \* Glass passivated junction

#### MECHANICAL DATA

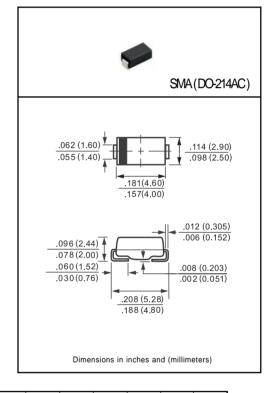
\* Case: Molded plastic

\* Epoxy: UL 94V-0 rate flame retardant \*Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

\* Polarity: As marked \* Mounting position: Any \* Weight: 0.064 gram

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



			GS1A	GS1B	GS1D	GS1G	GS1J	GS1K	GS1M	
		SYMBOL	M1	M2	M3	M4	M5	M6	M7	UNITS
Maximum Recurrent Peak Reverse Voltage		VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA = 75°C		lo	1.0							Amps
Peak Forward Surge Current IFM(surge): 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)		IFSM	30						Amps	
Maximum Forward Voltage at 1.0A DC		VF	1.1						Volts	
Maximum DC Reverse Current at	@Ta = 25°C	l <sub>R</sub>	5.0							uAmps
Rated DC Blocking Voltage	@TA = 125°C	IK IK	50							
Maximum Reverse Recovery Time (Note 3)		trr	2.5						uSec	
Typical Thermal Resistance (Note 2)		RθJL	30							°C/W
Typical Junction Capacitance (Note 1)		CJ	15							pF
Operating and Storage Temperature Range		TJ, TSTG	-65 to + 175							٥C

NOTES: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0VDC

- 2. Thermal Resistance (Junction to Ambient), .24in² (6.0mm²) copper pads to each terminal.
- 3. Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A.

#### RATING AND CHARACTERISTIC CURVES

GS1A GS1M THRU M7

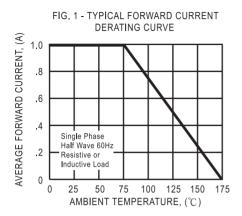


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PEAK FORWARD SURGE CURRENT, (A) 50 40 30 20 10 8.3ms Single Half Sine-Wave (JEDEC Method) 0 6 8 10 60 80 100 20 40 NUMBER OF CYCLES AT 60Hz

FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

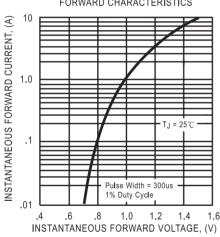


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

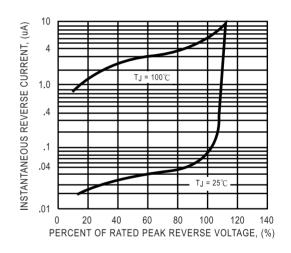
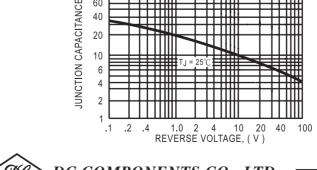


FIG. 5 - TYPICAL JUNCTION CAPACITANCE 200 JUNCTION CAPACITANCE, (pF) 100 60 40 20 10 6 4 2 1 .1 .2 40





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